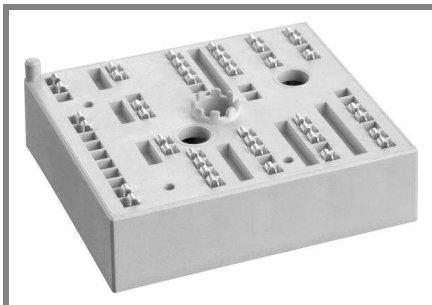


SKiiP 28GH066V1



MiniSKiiP[®]2

H-bridge inverter

SKiiP 28GH066V1

Features

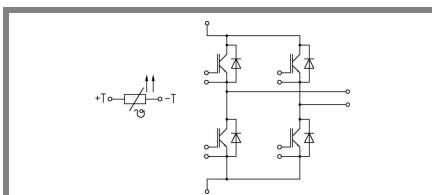
- Trench IGBTs
- Robust and soft freewheeling diode in CAL technology
- Highly reliable spring contacts for electrical connection
- UL recognised file no. E63532

Typical Applications*

- Single-phase inverter up to 16 kVA
- Single-phase motor power 7.5 kW

Remarks

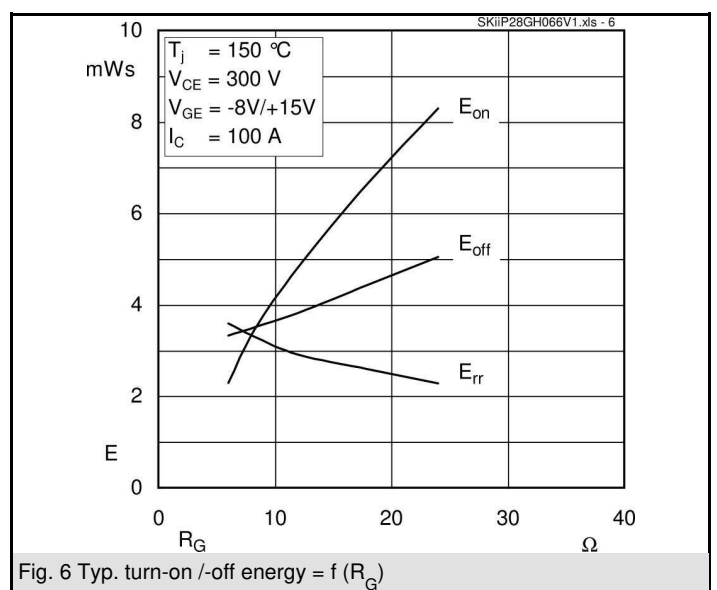
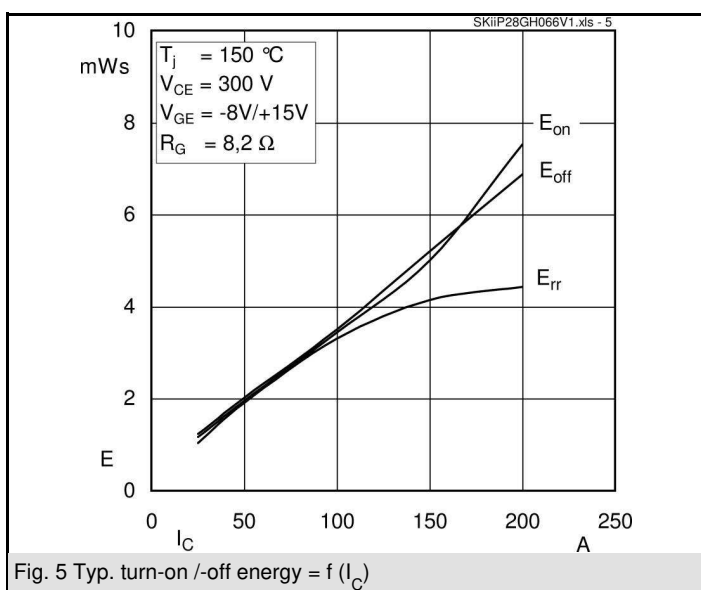
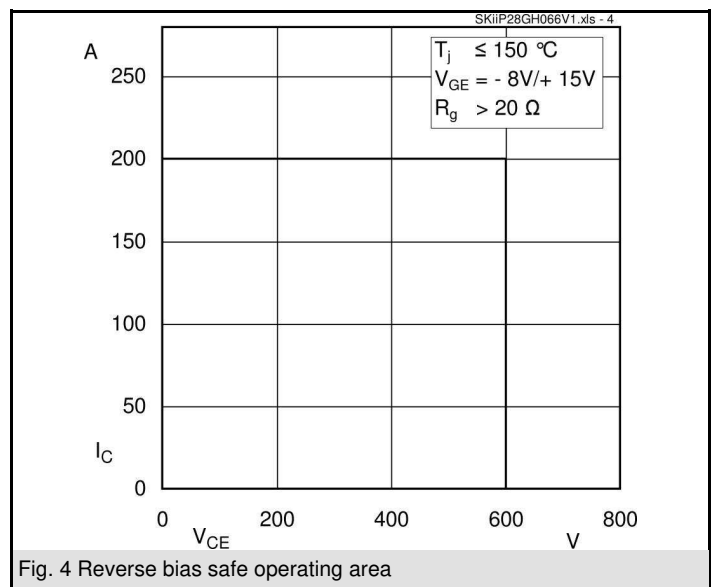
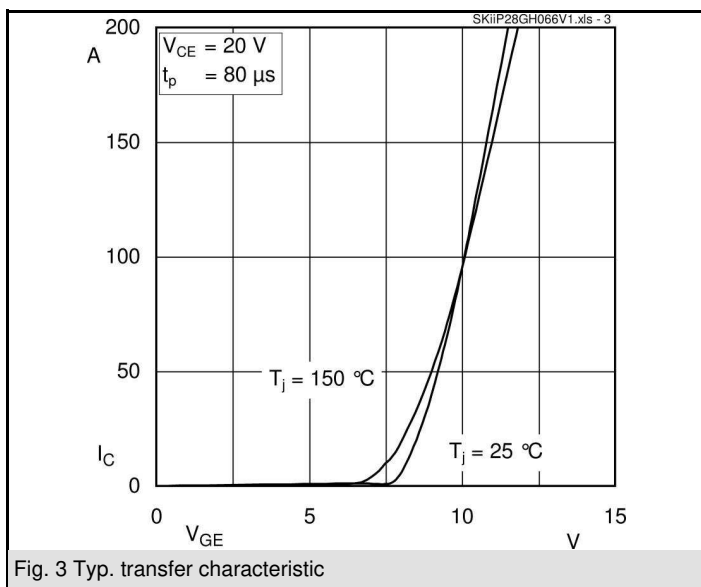
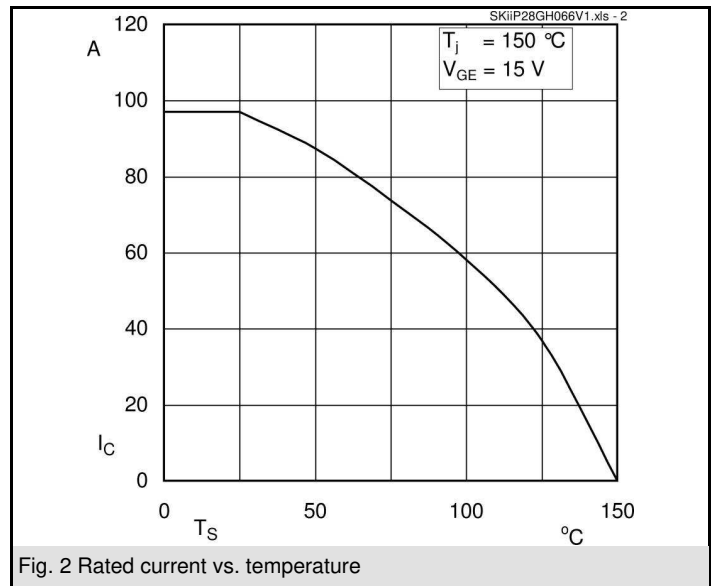
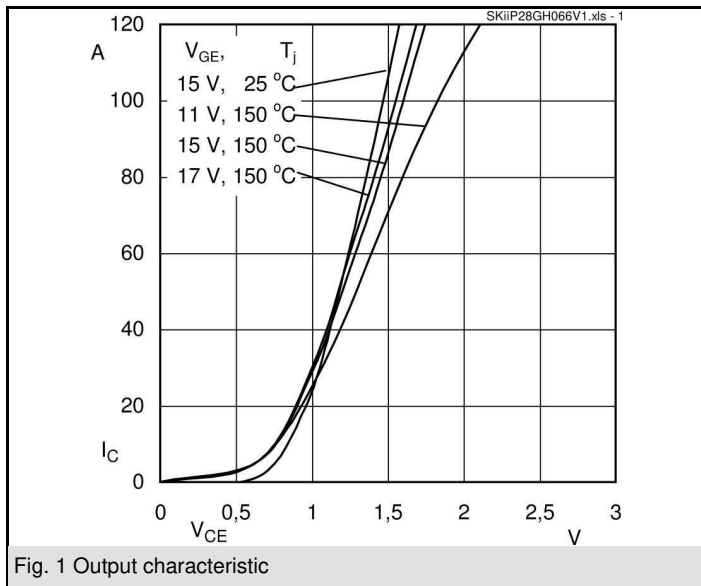
- Case temperature limited to $T_C = 125^\circ\text{C}$
- Product reliability results are valid for $T_j = 150^\circ\text{C}$
- SC data: $t_p \leq 6 \text{ s}$; $V_{GE} \leq 15 \text{ V}$; $T_j = 150^\circ\text{C}$, $V_{CC} = 360 \text{ V}$
- V_{CEsat} , $V_F =$ chip level value



GH

Absolute Maximum Ratings		$T_S = 25^\circ\text{C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT - Inverter			
V_{CES}		600	V
I_C	$T_S = 25 (70)^\circ\text{C}, T_j = 150^\circ\text{C}$	101 (68)	A
I_C	$T_S = 25 (70)^\circ\text{C}, T_j = 175^\circ\text{C}$	112 (83)	A
I_{CRM}	$t_p = 1 \text{ ms}$	200	A
V_{GES}		± 20	V
T_j		-40...+175	$^\circ\text{C}$
Diode - Inverter			
I_F	$T_S = 25 (70)^\circ\text{C}, T_j = 150^\circ\text{C}$	103 (67)	A
I_F	$T_S = 25 (70)^\circ\text{C}, T_j = 175^\circ\text{C}$	112 (81)	A
I_{FRM}	$t_p = 1 \text{ ms}$	200	A
T_j		-40...+175	$^\circ\text{C}$
I_{RMS}	per power terminal (20 A / spring)	100	A
T_{stg}	$T_{op} \leq T_{stg}$	-40...+125	$^\circ\text{C}$
V_{isol}	AC, 1 min.	2500	V

Characteristics		$T_S = 25^\circ\text{C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT - Inverter					
V_{CEsat}	$I_{Cnom} = 100 \text{ A}, T_j = 25 (150)^\circ\text{C}$	1,05	1,45 (1,65)	1,85 (2,05)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 2 \text{ mA}$		5,8		V
$V_{CE(TO)}$	$T_j = 25 (150)^\circ\text{C}$		0,9 (0,8)	1,1 (1)	V
r_T	$T_j = 25 (150)^\circ\text{C}$		5,5 (8,5)	7,5 (10,5)	m Ω
C_{ies}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		6,15		nF
C_{oes}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		1,12		nF
C_{res}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,9		nF
$R_{CC'+EE'}$	spring contact-chip $T_S = 25 (150)^\circ\text{C}$				m Ω
$R_{th(j-s)}$	per IGBT		0,6		K/W
$t_{d(on)}$	under following conditions		40		ns
t_r	$V_{CC} = 300 \text{ V}, V_{GE} = -8\text{V}/+15\text{V}$		40		ns
$t_{d(off)}$	$I_{Cnom} = 100 \text{ A}, T_j = 150^\circ\text{C}$		410		ns
t_f	$R_{Gon} = R_{Goff} = 8,2 \Omega$		50		ns
$E_{on}(E_{off})$	inductive load		3,4 (3,5)		mJ
Diode - Inverter					
$V_F = V_{EC}$	$I_{Fnom} = 100 \text{ A}, T_j = 25 (150)^\circ\text{C}$		1,3 (1,3)	1,5 (1,5)	V
$V_{(TO)}$	$T_j = 25 (150)^\circ\text{C}$		0,9 (0,8)	1 (0,9)	V
r_T	$T_j = 25 (150)^\circ\text{C}$		4 (5)	5 (6)	m Ω
$R_{th(j-s)}$	per diode		0,8		K/W
I_{RRM}	under following conditions		102		A
Q_{rr}	$I_{Fnom} = 100 \text{ A}, V_R = 300 \text{ V}$		15,5		C
E_{rr}	$V_{GE} = 0 \text{ V}, T_j = 150^\circ\text{C}$		3,3		mJ
	$di_F/dt = 2560 \text{ A/s}$				
Temperature Sensor					
R_{ts}	3 %, $T_r = 25 (100)^\circ\text{C}$		1000(1670)		Ω
Mechanical Data					
m			65		g
M_s	Mounting torque	2		2,5	Nm



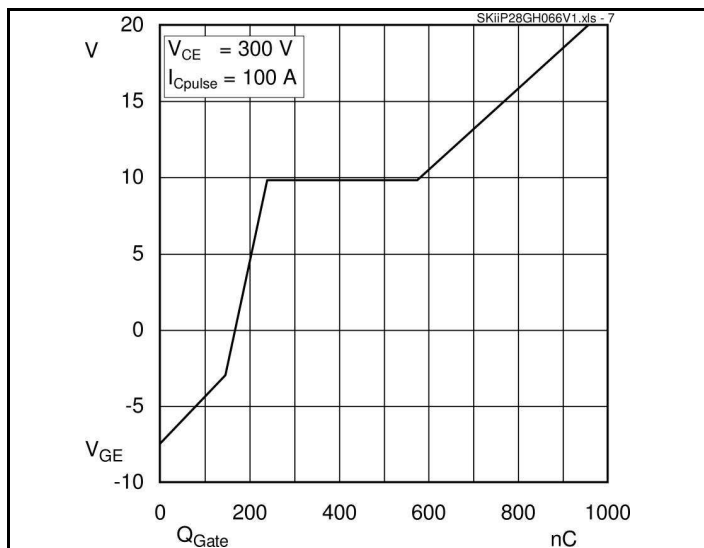


Fig. 7 Typ. Gate charge characteristic

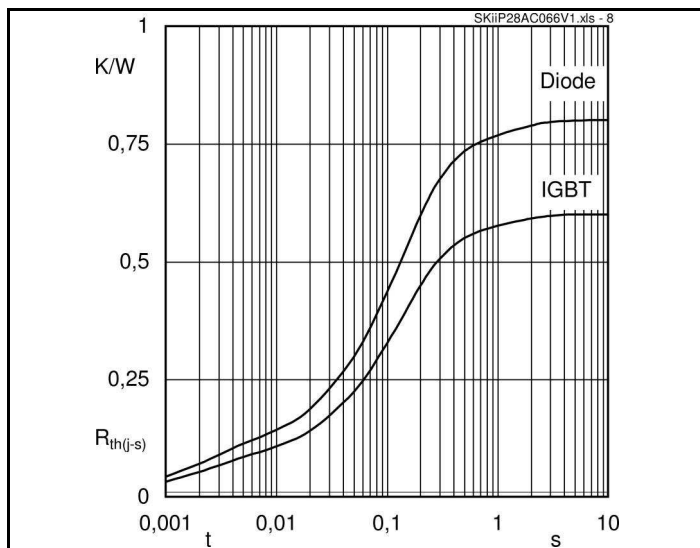


Fig. 8 Thermal impedance

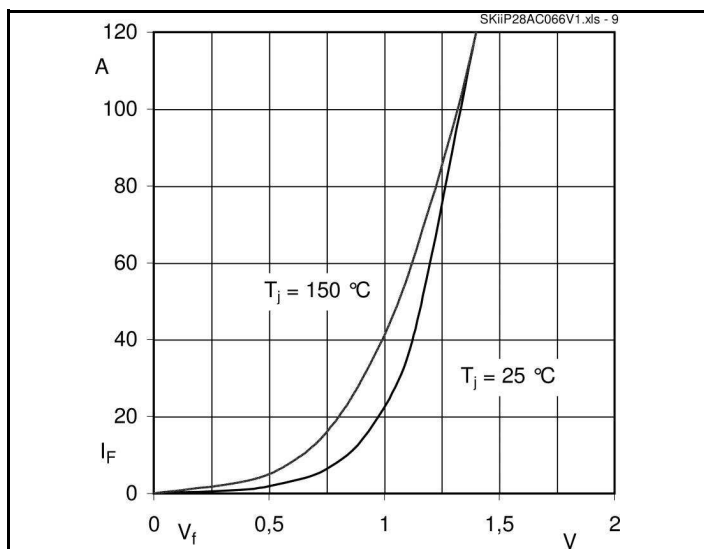
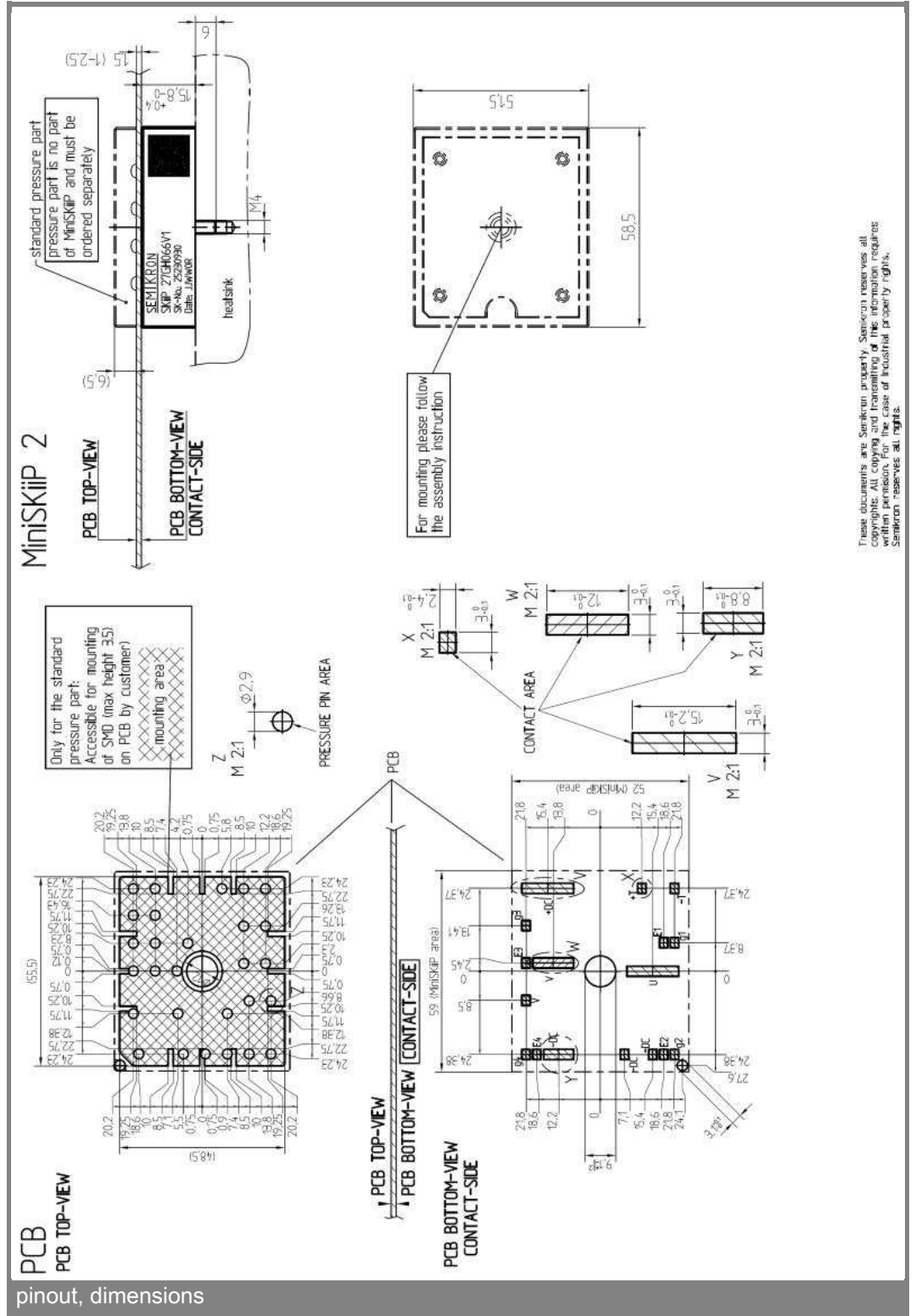
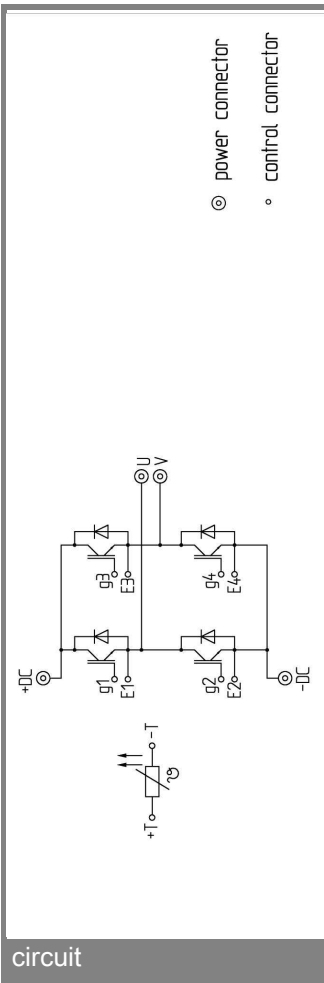


Fig. 9 Freewheeling diode forward characteristic



These documents are Semikron property. Semikron reserves all copyrights. All copying and transmitting of the information requires written permission. For the case of industrial property rights, Semikron reserves all rights.

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [IGBT Modules category](#):

Click to view products by [Semikron manufacturer](#):

Other Similar products are found below :

[F3L100R07W2E3_B11](#) [F3L15R12W2H3_B27](#) [F3L400R07ME4_B22](#) [F3L400R12PT4_B26](#) [F4-100R12KS4](#) [F4-50R07W2H3_B51](#) [F4-75R12KS4_B11](#) [FB15R06W1E3](#) [FB20R06W1E3_B11](#) [FD1000R33HE3-K](#) [FD300R06KE3](#) [FD300R12KE3](#) [FD300R12KS4_B5](#) [FD400R12KE3](#) [FD400R33KF2C-K](#) [FD401R17KF6C_B2](#) [FD-DF80R12W1H3_B52](#) [FF100R12KS4](#) [FF1200R17KE3_B2](#) [FF150R12KE3G](#) [FF200R06KE3](#) [FF200R06YE3](#) [FF200R12KT3](#) [FF200R12KT3_E](#) [FF200R12KT4](#) [FF200R17KE3](#) [FF300R06KE3_B2](#) [FF300R12KE4_E](#) [FF300R12KS4HOSA1](#) [FF300R12ME4_B11](#) [FF300R12MS4](#) [FF300R17ME4](#) [FF450R12ME4P](#) [FF450R17IE4](#) [FF600R12IE4V](#) [FF600R12IP4V](#) [FF800R17KP4_B2](#) [FF900R12IE4V](#) [MIXA30W1200TED](#) [MIXA450PF1200TSF](#) [FP06R12W1T4_B3](#) [FP100R07N3E4](#) [FP100R07N3E4_B11](#) [FP10R06W1E3_B11](#) [FP10R12W1T4_B11](#) [FP10R12YT3](#) [FP10R12YT3_B4](#) [FP150R07N3E4](#) [FP15R12KT3](#) [FP15R12W2T4](#)